ABSOLUTE MAXIMUM RATINGS

(Note 1)

V _{IN} to GND	0.3V to 6V
V _{OUT} to GND	0.3V to 6V
SHDN to GND	0.3V to 6V
V _{OUT} Short-Circuit Duration	Indefinite

Commercial Temperature Range 0°C to 70°C
Extended Commercial Operating
Temperature Range (Note 2) -40° C to 85° C
Storage Temperature Range –65°C to 150°C
Lead Temperature (Soldering, 10 sec) 300°C

PACKAGE/ORDER INFORMATION



Consult factory for Industrial and Military grade parts.

ELECTRICAL CHARACTERISTICS

 V_{IN} = 2.7V to 5V, C_{FLY} = 0.22 μ F, C_{IN} = C_{OUT} = 10 μ F, T_{MIN} to T_{MAX} unless otherwise specified. (Note 2)

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
V _{IN}	Input Voltage			2.7		5	V
V _{OUT}	Output Voltage	$2.7V \le V_{IN} \le 5V$, $I_{OUT} \le 10$ mA	•	4.8	5.0	5.2	V
		$3V \le V_{IN} \le 5V$, $I_{OUT} \le 20mA$	•	4.8	5.0	5.2	V
I _{CC}	Operating Supply Current	$2.7V \le V_{IN} \le 5V$, $I_{OUT} = 0mA$, SHDN = 0V	•		6	15	μA
	Shutdown Supply Current	$2.7V \le V_{IN} \le 3.6V$, $I_{OUT} = 0mA$, SHDN = V_{IN}	•		0.005	1	μA
		$3.6V < V_{IN} \le 5V$, $I_{OUT} = 0mA$, SHDN = V_{IN}	•			2.5	μA
	Output Ripple	V _{IN} = 3V, I _{OUT} = 10mA			70		mV _{P-P}
	Efficiency	$V_{IN} = 3V$, $I_{OUT} = 10mA$			82		%
f _{OSC}	Switching Frequency	Oscillator Free Running			700		kHz
VIH	SHDN Input Threshold		•			(0.7)(V _{IN})	V
V _{IL}			•	0.4			V
I _{IH}	SHDN Input Current	V _{SHDN} = V _{IN}	•	-1		1	μA
I _{IL}		V _{SHDN} = 0V	•	-1		1	μA
t _{ON}	V _{OUT} Turn-On Time	$V_{IN} = 3V, I_{OUT} = 0mA$			1		ms

The \bullet denotes specifications which apply over the specified temperature range.

Note 1: Absolute Maximum Ratings are those values beyond which the life of the device may be impaired.

Note 2: C grade device specifications are guaranteed over the 0°C to 70°C temperature range. In addition, C grade device specifications are assured over the -40°C to 85°C temperature range by design or correlation, but are not production tested.



TYPICAL PERFORMANCE CHARACTERISTICS



PIN FUNCTIONS

NC (Pin 1): No Connect.

 V_{IN} (Pin 2): Input Supply Voltage. Bypass V_{IN} with a $\geq 3.3 \mu F$ low ESR capacitor.

V_{OUT} (**Pin 3**): 5V Output Voltage (V_{OUT} = 0V in Shutdown). Bypass V_{OUT} with $a \ge 3.3\mu$ F low ESR capacitor.

C+ (Pin 4): Flying Capacitor, Positive Terminal.

C⁻ (Pin 5): Flying Capacitor, Negative Terminal.

GND (Pin 6): Ground.

SHDN (Pin 7): Active High CMOS Logic-Level Shutdown Input. Drive SHDN low to enable the DC/DC converter. Do not float.

NC (Pin 8): No Connect.



BLOCK DIAGRAM



APPLICATIONS INFORMATION

Operation

The LTC1522 uses a switched capacitor charge pump to boost V_{IN} to a regulated 5V $\pm4\%$ output voltage. Regulation is achieved by sensing the output voltage through an internal resistor divider and enabling the charge pump when the output voltage droops below the lower trip point of COMP1. When the charge pump is enabled, a 2-phase, nonoverlapping clock controls the charge pump switches. Clock 1 closes the S1 switches which enables the flying capacitor to charge up to the VIN voltage. Clock 2 closes the S2 switches that stack C_{FLY} in series with V_{IN} and connect the top plate of C_{FLY} to the output capacitor at V_{OUT} . This sequence of charging and discharging continues at a free-running frequency of 700kHz (typ) until the output has risen to the upper trip point of COMP1 and the charge pump is disabled. When the charge pump is disabled, the LTC1522 draws only $4\mu A$ (typ) from V_{IN} which provides high efficiency at low load conditions.

In shutdown mode, all circuitry is turned off and the part draws only leakage current from the V_{IN} supply. V_{OUT} is also disconnected from V_{IN} . The SHDN pin is a CMOS input with a threshold of approximately $V_{IN}/2$; however, the SHDN pin can be driven by logic levels that exceed the V_{IN} voltage. The part enters shutdown mode when a logic

high is applied to the SHDN pin. The SHDN pin should not be floated; it must be driven with a logic high or low.

Short-Circuit/Thermal Protection

During short-circuit conditions, the LTC1522 will draw between 100mA and 200mA from V_{IN} causing a rise in the junction temperature. On-chip thermal shutdown circuitry disables the charge pump once the junction temperature exceeds $\approx 160^{\circ}$ C, and reenables the charge pump once the junction temperature falls back to $\approx 145^{\circ}$ C. The LTC1522 will cycle in and out of thermal shutdown indefinitely without latchup or damage until the V_{OUT} short is removed.

Capacitor Selection

For best performance, it is recommended that low ESR (< 0.5Ω) capacitors be used for both C_{IN} and C_{OUT} to reduce noise and ripple. The C_{IN} and C_{OUT} capacitors should be either ceramic or tantalum and should be 3.3μ F or greater (aluminum capacitors are not recommended because of their high ESR). If the input source impedance is very low, C_{IN} may not be needed. Increasing the size of C_{OUT} to 10μ F or greater will reduce output voltage ripple.



APPLICATIONS INFORMATION

A ceramic capacitor is recommended for the flying capacitor with a value in the range of 0.1μ F to 0.22μ F. Note that a large value flying cap (> 0.22μ F) will increase output ripple unless C_{OUT} is also increased. For very low load applications, C_{FLY} may be reduced to 0.01μ F to 0.047μ F. This will reduce output ripple at the expense of efficiency and maximum output current.

Output Ripple

Normal LTC1522 operation produces voltage ripple on the V_{OUT} pin. Output voltage ripple is required for the LTC1522 to regulate. Low frequency ripple exists due to the hysteresis in the sense comparator and propagation delays in the charge pump enable/disable circuits. High frequency ripple is also present mainly due to ESR (Equivalent Series Resistance) in the output capacitor. Typical output ripple under maximum load is 50mV_{P-P} with a low ESR 10µF output capacitor.

The magnitude of the ripple voltage depends on several factors. High input voltages (V_{IN} > 3.3V) increase the output ripple since more charge is delivered to C_{OUT} per clock cycle. A large flying capacitor (>0.22µF) also increases ripple for the same reason. Large output current load and/ or a small output capacitor (<10µF) results in higher ripple due to higher output voltage dV/dt. High ESR capacitors (ESR > 0.5 Ω) on the output pin cause high frequency voltage spikes on V_{OUT} with every clock cycle.

There are several ways to reduce the output voltage ripple. A larger C_{OUT} capacitor (22µF or greater) will reduce both the low and high frequency ripple due to the lower C_{OUT} charging and discharging dV/dt and the lower ESR typically found with higher value (larger case size) capacitors. A low ESR ceramic output capacitor will minimize the high frequency ripple, but will not reduce the low frequency ripple unless a high capacitance value is chosen. A reasonable compromise is to use a 10µF to 22µF tantalum capacitor in parallel with a 1µF to 3.3µF ceramic capacitor on V_{OUT} to reduce both the low and high frequency ripple. An RC filter may also be used to reduce high frequency voltage spikes (see Figure 1).



Figure 1. Output Ripple Reduction Techniques

In low load or high V_{IN} applications, smaller values for C_{FLY} may be used to reduce output ripple. A smaller flying capacitor (0.01µF to 0.047µF) delivers less charge per clock cycle to the output capacitor resulting in lower output ripple. However, the smaller value flying caps also reduce the maximum I_{OUT} capability as well as efficiency.

Inrush Currents

During normal operation, V_{IN} will experience current transients in the 50mA to 100mA range whenever the charge pump is enabled. During start-up, these inrush currents may approach 250mA. For this reason, it is important to minimize the source resistance between the input supply and the V_{IN} pin. Too much source resistance may result in regulation problems or even prevent start-up.

Ultralow Quiescent Current (I_Q = 2.1 μ A) Regulated Supply

The LTC1522 contains an internal resistor divider (refer to the Block Diagram) that draws only 1 μ A (typ) from V_{OUT}. During no-load conditions, the internal load causes a droop rate of only 100mV per second on V_{OUT} with C_{OUT} = 10 μ F. Applying a 2Hz to 100Hz, 95% to 98% duty cycle signal to the SHDN pin ensures that the circuit of Figure 2 comes out of shutdown frequently enough to maintain regulation during no-load or low-load conditions. Since the part spends nearly all of its time in shutdown, the no-load quiescent current (see Figure 3a) is approximately equal to (V_{OUT})(1 μ A)/(V_{IN})(Efficiency).



APPLICATIONS INFORMATION







Figure 3a. No-Load $I_{\mbox{CC}}$ vs Input Voltage for Circuit in Figure 3

The LTC1522 must be out of shutdown for a minimum duration of 200 μ s to allow enough time to sense the output and keep it in regulation. A 2Hz, 98% duty cycle signal will keep V_{OUT} in regulation under no-load conditions. As the V_{OUT} load current increases, the frequency with which the part is taken out of shutdown must also be increased to prevent V_{OUT} from drooping below 4.8V during the OFF phase (see Figure 3b). A 100Hz 98% duty cycle signal on the SHDN pin ensures proper regulation with load currents as high as 100 μ A. When load current greater than 100 μ A is needed, the SHDN pin must be forced low as in normal operation. The typical no-load supply current for this circuit with V_{IN} = 3V is only **2.1** μ **A**.



Figure 3b. Maximum SHDN OFF Time vs Output Load Current for Ultralow $I_{\mbox{\scriptsize O}}$ Operation

Each time the LTC1522 comes out of shutdown, the part delivers a minimum of one clock cycle worth of charge to the output. Under high V_{IN} (>3.3V) and/or low I_{OUT} (<10 μ A) conditions, this behavior may cause a net excess of charge to be delivered to the output capacitor if a high frequency signal is used on the SHDN pin (e.g., 50Hz to 100Hz). Under such conditions, V_{OUT} will slowly drift positive and may even go out of regulation. To avoid this potential problem in the low I_Q mode, it is necessary to switch the part in and out of shutdown at the minimum allowable frequency (refer to Figure 3b) for a given output load.



APPLICATIONS INFORMATION

General Layout Considerations

Due to the high switching frequency and high transient currents produced by the LTC1522, careful board layout is a must. A clean board layout using a ground plane and short connections to all capacitors will improve performance and ensure proper regulation under all conditions (refer to Figure 4).





PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.



SHALL NOT EXCEED 0.006" (0.152mm) PER SIDE *DIMENSION DOES NOT INCLUDE INTERLEAD FLASH, INTERLEAD

FLASH SHALL NOT EXCEED 0.010" (0.254mm) PER SIDE

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TYPICAL APPLICATION



Programmable 5V/3V SIM Interface Supply for GSM Cellular Phones

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS	
LTC1144	20mA Switched Capacitor Converter for Up to 20V Inputs	Includes Micropower Shutdown (8µA)	
LTC1262	5V to 12V Regulated Switched Capacitor Converter	Up to 30mA at Regulated Output	
LTC1514/15	Step-Up/Step-Down Switched Capacitor DC/DC Converters	$V_{\rm IN}$ 2V to 10V, $V_{\rm OUT}$ is Fixed or Adjustable, $I_{\rm OUT}$ to 50mA	
LTC1516	Micropower, Regulated 5V Charge Pump DC/DC Converter	I_{OUT} = 20mA (V _{IN} \ge 2V), I_{OUT} = 50mA (V _{IN} \ge 3V)	
LTC1517-5	Micropower, Regulated 5V Charge Pump DC/DC Converter	LTC1522 Without Shutdown and Packaged in SOT-23	
LTC1555/56	SIM Power Supply and Level Translator	Step-Up/Step-Down SIM Power Supply and Level Translators	
LTC660	100mA CMOS Voltage Converter	5V to -5V Conversion with Low Voltage Loss	